



**TET ESTEL AS**  
ESTONIA

**July**  
**2013**

**Series**  
**DL353-1600**

**Avalanche Rectifier Press-Pack**  
**Diode**  
**Type DL353-1600**

Guaranteed maximum avalanche power dissipation.  
Designed for rectifiers and industrial applications.

Maximum mean forward current	$I_{FAV}$	<b>1600 A</b>				
Maximum repetitive peak reverse voltage	$U_{RRM}$	<b>2200 ÷ 3200 V</b>				
Surge reverse power dissipation	$P_{RSM}$	<b>16kW</b>				
Reverse recovery time	$t_{rr}$ (typ)	<b>50 <math>\mu</math>s</b>				
$U_{RRM}$ , V	2200	2400	2600	2800	3000	3200
Voltage code	22	24	26	28	30	32
$T_{vj}$ , °C	- 60 ÷ 175					

**MAXIMUM ALLOWABLE RATINGS**

Symbols and parameters		Units	DL353-1600	Conditions
$I_{FAV}$	Mean forward current	A	1600 2310	$T_c=107^\circ\text{C}$ , $T_c=55^\circ\text{C}$ , 180° half-sine wave, 50 Hz
$I_{FRMS}$	RMS forward current	A	2512	$T_c=107^\circ\text{C}$
$I_{FSM}$	Surge forward current	kA	28 30	$T_{vj}=175^\circ\text{C}$ $T_{vj}=25^\circ\text{C}$ tp=10 ms $U_R=0$
$I^2t$	Limiting load integral	$\text{kA}^2\text{s}$	3920 4500	$T_{vj}=175^\circ\text{C}$ $T_{vj}=25^\circ\text{C}$
$U_{RRM}$	Repetitive peak reverse voltage	V	2200÷3200	$T_j \text{ min} \leq T_{vj} \leq T_{jM}$ 180° half-sine wave, 50 Hz
$U_{BR}$	Reverse breakdown voltage	V	2750÷4000	$T_j \text{ min} \leq T_{vj} \leq T_{jM}$ 180° half-sine wave, 50 Hz $I_R=10\text{mA}$
$P_{RSM}$	Surge reverse power dissipation	kW	16	$T_{vj}=175^\circ\text{C}$ ; tp=100 $\mu$ s; 180° half-sine wave
$T_{stg}$	Storage temperature	°C	-60÷80	
$T_{vj}$	Junction temperature	°C	-60÷175	

**CHARACTERISTICS**

$U_{FM}$	Peak forward voltage	V	2,0	$T_{vj}=25^\circ\text{C}$ , $I_{TM}=3,14 I_{TAV}$
$U_{F(TO)}$	Threshold voltage	V	0,95	$T_{vj}=175^\circ\text{C}$ 1,57 $I_{TAV} < I_T < 4,71 I_{TAV}$
$R_T$	Forward slope resistance	m $\Omega$	0,29	

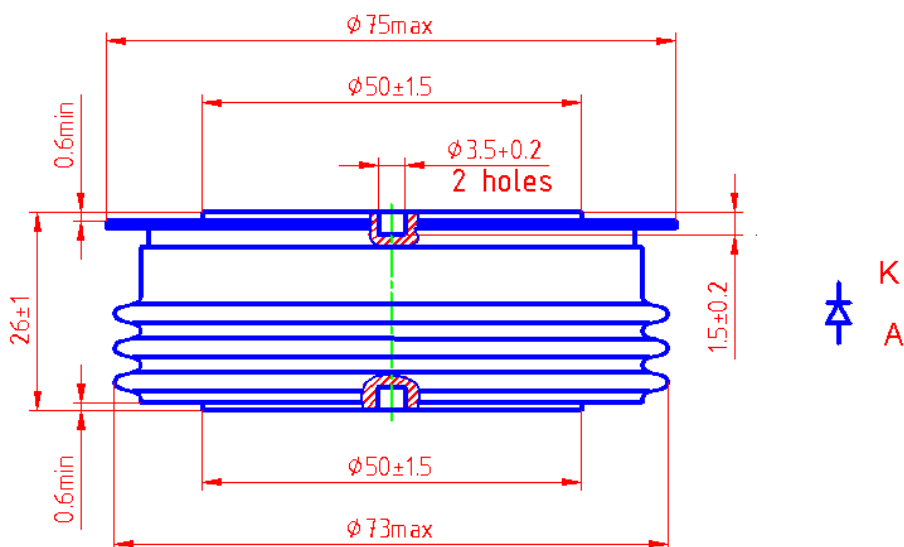
## CHARACTERISTICS

Symbols and parameters		Units	DL353-1600	Conditions
$I_{RRM}$	Repetitive peak reverse current	mA	100	$T_{vj}=175^{\circ}\text{C}$ , $U_R=U_{RRM}$
$Q_{rr}$	Recovered charge (typ)	$\mu\text{C}$	5000	$T_{vj}=175^{\circ}\text{C}$ $I_F=1600\text{ A}$ $di_R/dt=10\text{ A}/\mu\text{s}$ $U_R=100\text{V}$
$t_{rr}$	Reverse recovery time (typ)	$\mu\text{s}$	50	
$I_{rrm}$	Peak reverse recovery current (typ)	A	200	
$R_{thjc}$	Thermal resistance junction to case	$^{\circ}\text{C}/\text{W}$	0,02	Direct current, double side cooled

## ORDERING

	DL	353	1600	30	
	1	2	3	4	

1. Avalanche diode
2. Design version
3. Mean forward current, A
4. Voltage code (30=3000 V)



Mounting force : 19 ÷ 28 kN  
Weight : 580 grams